

#### N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = 25℃		
60V	7.5Ω @ V <sub>GS</sub> = 5V	115mA		

### **Description and Applications**

This new generation MOSFET has been designed to minimize the onstate resistance ( $R_{DS(on)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

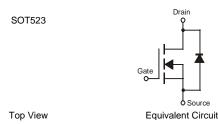
- DC-DC Converters
- Power management functions
- · Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc

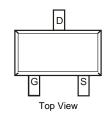
#### **Features**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- Totally Lead Free, Full RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Notes 2 and 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT523
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.002 grams (approximate)





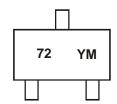
#### **Ordering Information** (Note 4)

Part Number	Qualification	Case	Packaging
2N7002T-7-F	Commercial	SOT523	3.000/Tape & Reel
2N7002T-13-F	Commercial	SOT523	10.000/Tape & Reel
2N7002TQ-7-F	Automotive	SOT523	3.000/Tape & Reel
2N7002TQ-13-F	Automotive	SOT523	10,000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. No purposely added lead. Halogen and Antimony free
- 2. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 3. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb<sub>2</sub>O<sub>3</sub> Fire Retardants
- 4. For packaging details, go to our website at http://www.diodes.com.

## **Marking Information**



72 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: T = 2006) M = Month (ex: 9 = September)

Date Code Key

Year	2005		2006	2007		2008	2009		2010	2011		2012
Code	S		Т	U		V	W		Χ	Y		Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

April 2012

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# Maximum Ratings @T<sub>A</sub> = 25℃ unless otherwise specified

Charact	eristic	Symbol	Value	Units
Drain-Source Voltage		$V_{DSS}$	60	V
Drain-Gate Voltage R <sub>GS</sub> ≤ 1.0MΩ		$V_{DGR}$	60	V
Gate-Source Voltage	Continuous Pulsed	V <sub>GSS</sub>	±20 ±40	V
Drain Current (Note 5)	Continuous Continuous @ 100℃ Pulsed	I <sub>D</sub>	115 73 800	mA

## Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	$P_d$	150	mW
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	833	℃/W
Operating and Storage Temperature Range	$T_{j,} T_{STG}$	-55 to +150	Ç

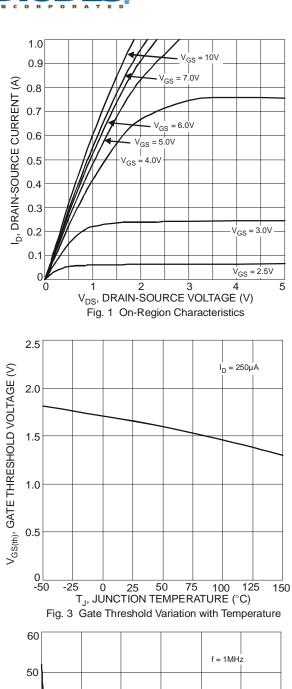
## Electrical Characteristics @TA = 25°C unless otherwise specified

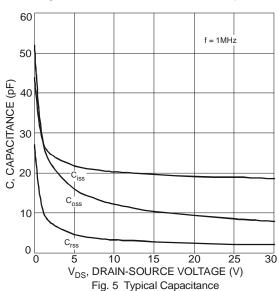
Chamastanistic		Compleal	NA:	T	Marr	I I m it	Toot Condition
Characteristic	;	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)		_					
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0V, I_{D} = 10\mu A$
Zero Gate Voltage Drain Current	@ T <sub>C</sub> = 25℃	I <sub>DSS</sub>			1.0	μA	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V
	@ T <sub>C</sub> = 125℃	יטכט			500	μ, ,	VDS = 00V, VGS = 0V
Gate-Body Leakage		I <sub>GSS</sub>	_	_	±10	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage		V <sub>GS(th)</sub>	1.0	_	2.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance	@ T <sub>i</sub> = 25℃	Ь		2.0	7.5	Ω	$V_{GS} = 5.0V, I_D = 0.05A$
	@ T <sub>j</sub> = 125℃	R <sub>DS</sub> (ON)	_	4.4	13.5	52	$V_{GS} = 10V, I_D = 0.5A$
On-State Drain Current		I <sub>D(ON)</sub>	0.5	1.0	_	Α	$V_{GS} = 10V, V_{DS} = 7.5V$
Forward Transconductance		g <sub>FS</sub>	80	_	_	mS	$V_{DS} = 10V, I_D = 0.2A$
DYNAMIC CHARACTERISTICS (Note 7	7)						
Input Capacitance		C <sub>iss</sub>	_	22	50	pF	
Output Capacitance		Coss	_	11	25	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance		C <sub>rss</sub>	_	2.0	5.0	pF	
SWITCHING CHARACTERISTICS (Not	e 7)						
Turn-On Delay Time		t <sub>D(ON)</sub>	_	7.0	20	ns	$V_{DD} = 30V, I_D = 0.2A,$
Turn-Off Delay Time		t <sub>D(OFF)</sub>	_	11	20	ns	$R_L = 150\Omega$ , $V_{GEN} = 10V$ , $R_{GEN} = 25\Omega$

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. 6 .Short duration pulse test used to minimize self-heating effect.
- 7. Guaranteed by design. Not subject to production testing.







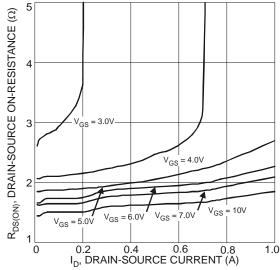


Fig. 2 On-Resistance Variation with Gate Voltage and Drain-Source Current

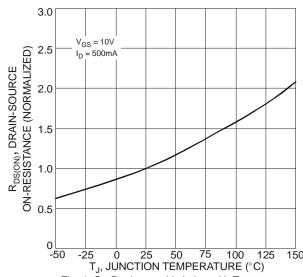
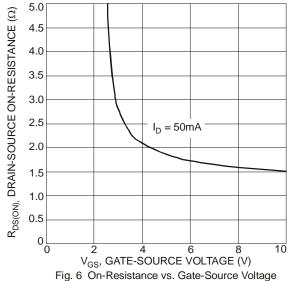
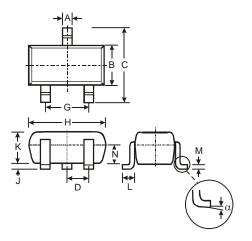


Fig. 4 On-Resistance Variation with Temperature



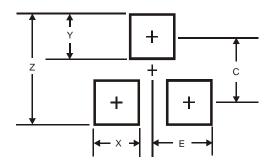


# **Package Outline Dimensions**



SOT523							
Dim	Min	Max	Тур				
Α	0.15	0.30	0.22				
В	0.75	0.85	0.80				
C	1.45	1.75	1.60				
D	_	_	0.50				
G	0.90	1.10	1.00				
Η	1.50	1.70	1.60				
J	0.00	0.10	0.05				
K	0.60	0.80	0.75				
L	0.10	0.30	0.22				
М	0.10	0.20	0.12				
N	0.45	0.65	0.50				
α	0°	8°	_				
All Dimensions in mm							

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	1.8
Х	0.4
Υ	0.51
С	1.3
E	0.7



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